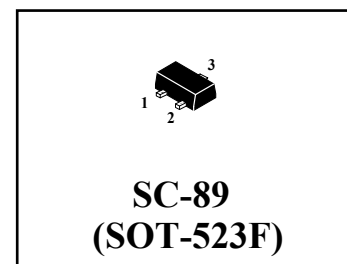
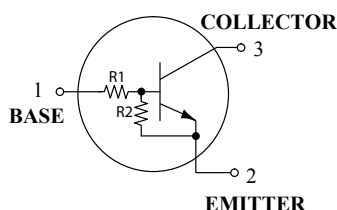


Bias Resistor Transistor NPN Silicon

(Pb) Lead(Pb)-Free



Maximum Ratings (TA=25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	50	V
Collector-Base Voltage	V_{CBO}	50	V
Collector Current-Continuous	I_C	100	mA

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Total Device Dissipation FR-5 Board FR-4 Board ⁽¹⁾ TA=25°C Derate above 25°C	P_D	200 1.6	mW mW/°C
Thermal Resistance, Junction to Ambient ⁽¹⁾	$R_{\theta JA}$	600	°C/W
Total Device Dissipation FR-5 Board FR-4 Board ⁽²⁾ TA=25°C Derate above 25°C	P_D	300 2.4	mW mW/°C
Thermal Resistance, Junction to Ambient ⁽²⁾	$R_{\theta JA}$	400	°C/W
Junction Temperature Range	T_J	-55 to +150	°C
Storage Temperature Range	T_{stg}	-55 to +150	°C

1.FR-4 @ Minimum pad

2.FR-4 @1.0 x 1.0 Inch pad

Device Marking and Resistor Values

Device	Marking	R1(K)	R2(K)
DTC114EE	8A	10	10
DTC124EE	8B	22	22
DTC144EE	8C	47	47
DTC114YE	8D	10	47
DTC114TE	94	10	∞
DTC143TE	8F	4.7	∞

Device	Marking	R1(K)	R2(K)
DTC123EE	8H	2.2	2.2
DTC143EE	8J	4.7	4.7
DTC143ZE	8K	4.7	47
DTC124XE	8L	22	47
DTC123JE	8M	2.2	47
DTC115EE	8N	100	100
DTC144WE	8P	47	22

Electrical Characteristics ($T_A=25^{\circ}\text{C}$ Unless Otherwise noted)

Characteristics	Symbol	Min	Typ	Max	Unit
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Off Characteristics

Collector-Emitter Breakdown Voltage ⁽²⁾ $I_C=2.0\text{mA}$, $I_B=0$		$V_{(BR)CEO}$	50	-	-	V
Collector-Base Breakdown Voltage $I_C=10\mu\text{A}$, $I_E=0$		$V_{(BR)CBO}$	50	-	-	V
Collector-Base Cutoff Voltage $V_{CB}=50\text{V}$, $I_E=0$		I_{CBO}	-	-	100	nA
Collector-Emitter Cutoff Current $V_{CE}=50\text{V}$, $I_B=0$		I_{CEO}	-	-	500	nA
Emitter-Base Cutoff Current $V_{EB}=6.0\text{V}$, $I_C=0$	DTC114EE	I_{EBO}	-	-	0.5	mA
	DTC124EE		-	-	0.2	
	DTC144EE		-	-	0.1	
	DTC114YE		-	-	0.2	
	DTC114TE		-	-	0.9	
	DTC143TE		-	-	1.9	
	DTC123EE		-	-	2.3	
	DTC143EE		-	-	1.5	
	DTC143ZE		-	-	0.18	
	DTC124XE		-	-	0.13	
	DTC123JE		-	-	0.2	
	DTC115EE		-	-	0.05	
	DTC144WE		-	-	0.13	

2. Pulse Test: Pulse Width < 300us, Duty Cycle < 2.0%

Electrical Characteristics (TA=25°C Unless Otherwise noted)

Characteristics	Symbol	Min	Typ	Max	Unit
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On Characteristics⁽³⁾

DC Current Gain V _{CE} =-10V, I _C =5.0mA	DTC114EE DTC124EE DTC144EE DTC114YE DTC114TE DTC143TE DTC123EE DTC143EE DTC143ZE DTC124XE DTC123JE DTC115EE DTC144WE	h _{FE}	35 60 80 80 160 160 8.0 15 80 80 80 80 80	60 100 140 140 250 250 15 27 140 130 140 150 140	- - - - - - - - - - - - -	-
Collector-Emitter Saturation Voltage I _C =10mA, I _E =0.3mA I _C =10mA, I _E =5.0mA I _C =10mA, I _E =1.0mA	DTC123EE DTC114TE / DTC143TE DTC143ZE / DTC124XE DTC143EE	V _{CE(sat)}	-	-	0.25	-
Output Voltage(on) V _{CC} =5.0V, V _B =2.5V R _L =1.0KΩ V _{CC} =5.0V, V _B =3.5V R _L =1.0KΩ V _{CC} =5.0V, V _B =5.5V R _L =1.0KΩ V _{CC} =5.0V, V _B =4.0V R _L =1.0KΩ	DTC114EE DTC124EE DTC144EE DTC114YE DTC114TE DTC143TE DTC123EE DTC143EE DTC143ZE DTC124XE DTC123JE DTC115EE DTC144WE	V _{OL}	-	-	0.2	V

3. Pulse Test: Pulse Width < 300us, Duty Cycle < 2.0%

Electrical Characteristics (TA=25°C Unless Otherwise noted)

Characteristics	Symbol	Min	Typ	Max	Unit
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On Characteristics⁽⁴⁾

Output Voltage(off) V _{CC} =5.0V, V _B =0.5V R _L =1.0KΩ V _{CC} =5.0V, V _B =0.25V R _L =1.0KΩ	DTC114TE DTC143TE DTC143ZE	V _{OH}	4.9	-	-	V
Input Resistor	DTC114EE DTC124EE DTC144EE DTC114YE DTC114TE DTC143TE DTC123EE DTC143EE DTC143ZE DTC124XE DTC123JE DTC115EE DTC144WE	R1	7.0 15.4 32.9 7.0 7.0 3.3 1.5 3.3 3.3 15.4 15.4 70 32.9	10 22 47 10 10 4.7 2.2 4.7 4.7 22 2.2 100 47	13 28.6 61.1 13 13 6.1 2.9 6.1 6.1 28.6 2.86 130 61.1	kΩ
Resistor Ratio	DTC114EE / DTC124EE DTC144EE / DTC115EE DTC114YE DTC114TE / DTC143TE DTC123EE / DTC143EE DTC143ZE DTC124XE DTC123JE DTC144WE	R1/R2	0.8 0.17 - 0.8 0.055 0.38 0.038 1.7	1.0 0.21 - 1.0 0.1 0.47 0.047 2.1	1.2 0.25 - 1.2 0.185 0.56 0.056 2.6	-

4. PulseTest: Pulse Width < 300us, Duty Cycle < 2.0%

DTC114EE Series

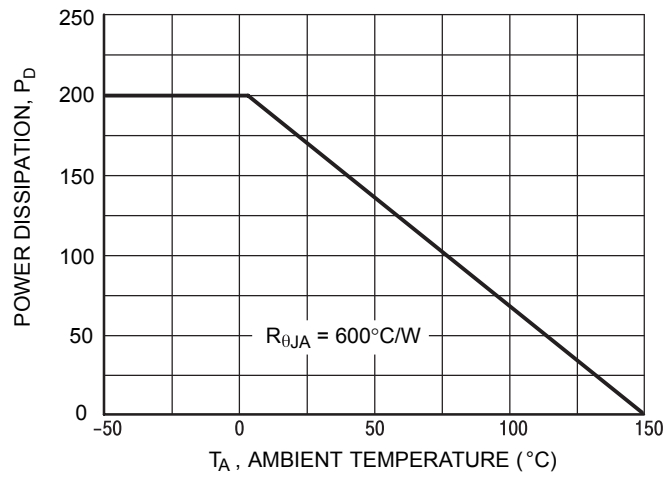


Figure 1. Derating Curve

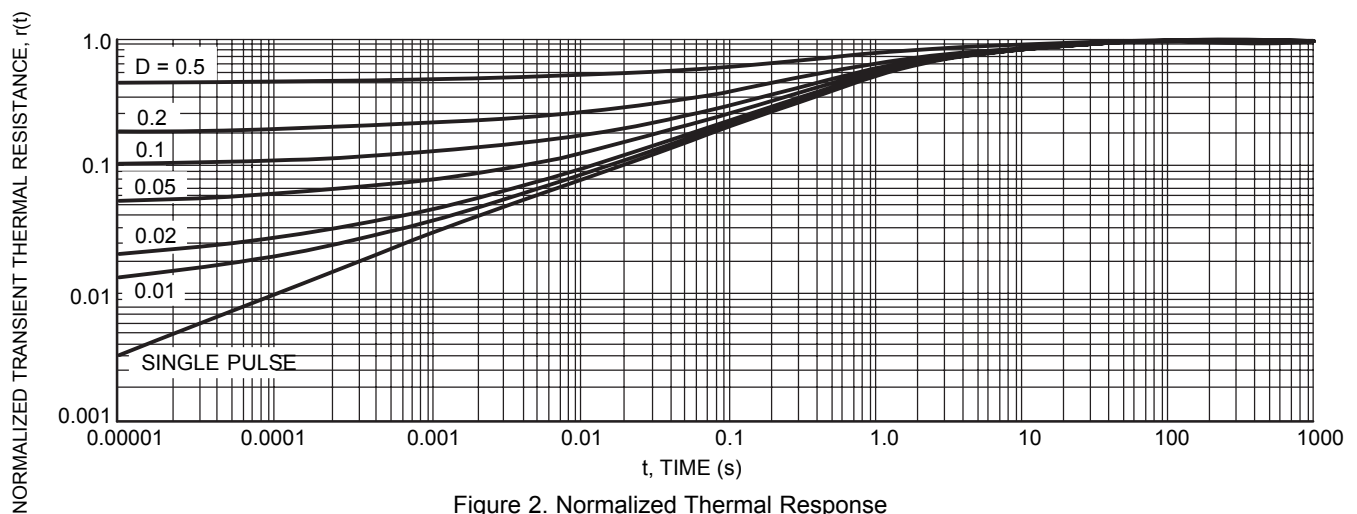


Figure 2. Normalized Thermal Response

TYPICAL ELECTRICAL CHARACTERISTICS – DTC114EE

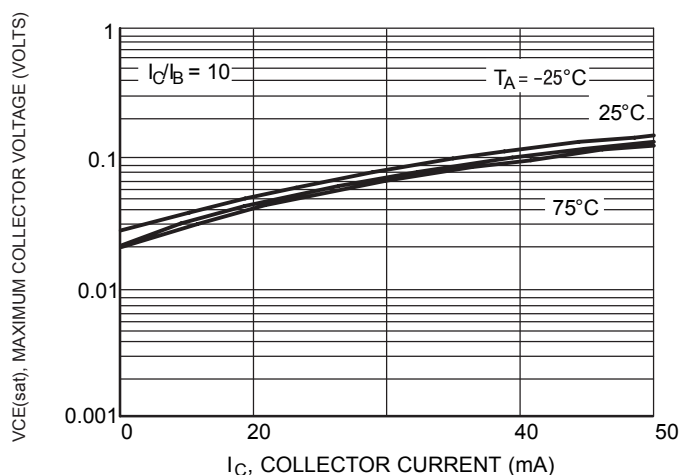


Figure 3. $V_{CE(sat)}$ versus I_C

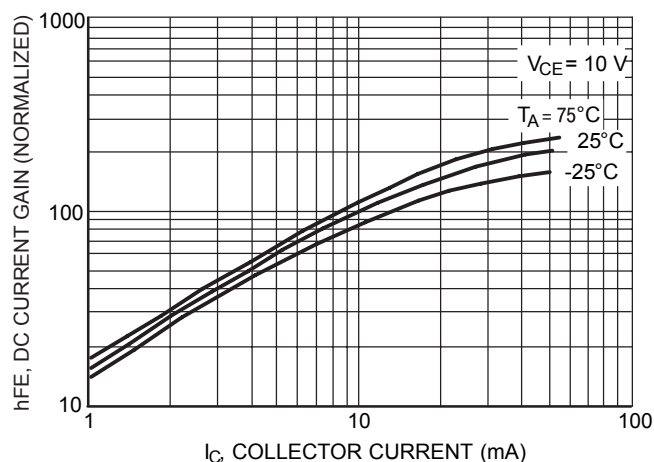


Figure 4. DC Current Gain

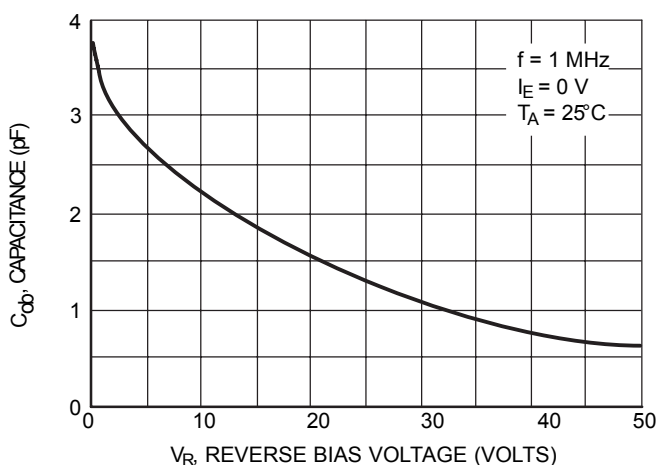


Figure 5. Output Capacitance

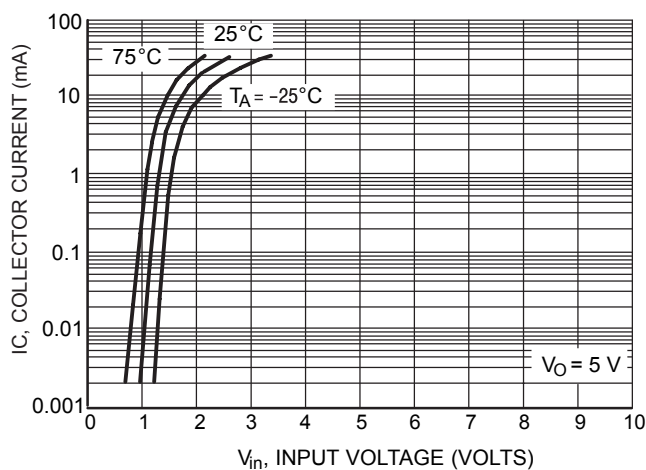


Figure 6. Output Current versus Input Voltage

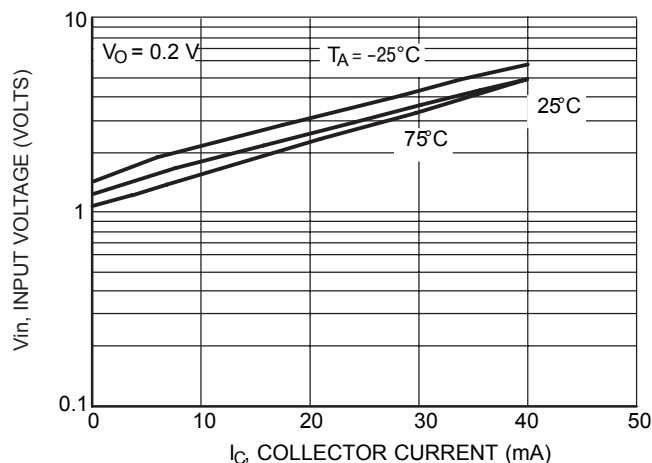


Figure 7. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS – DTC123EE

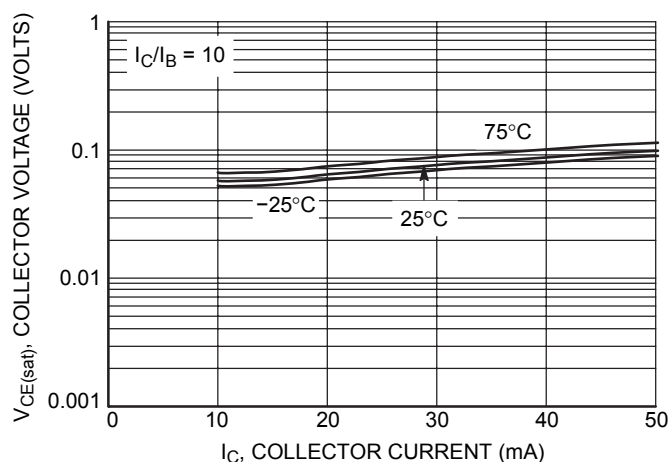


Figure 8. $V_{CE(sat)}$ versus I_C

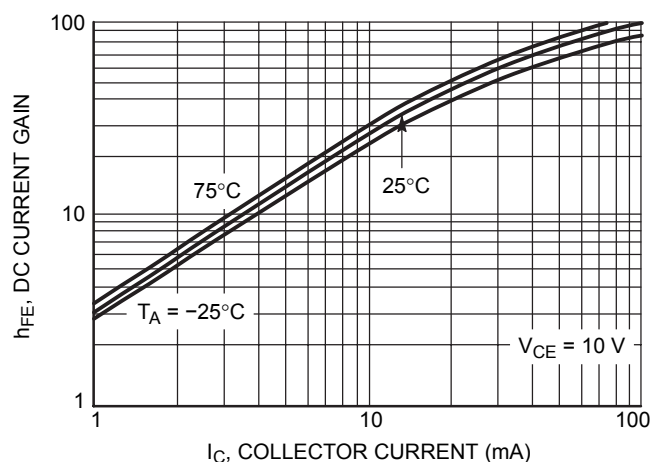


Figure 9. DC Current Gain

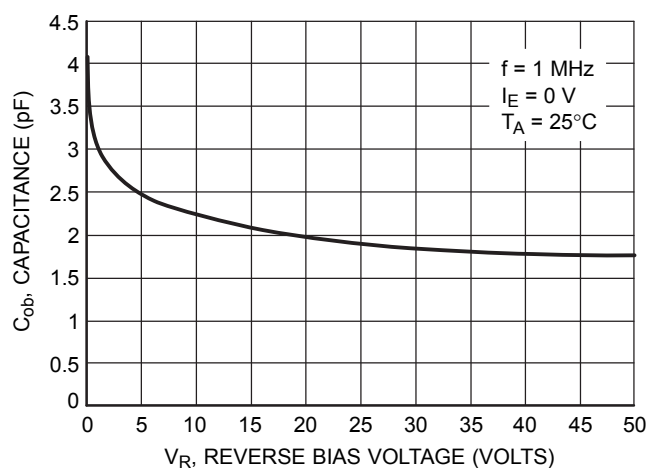


Figure 10. Output Capacitance

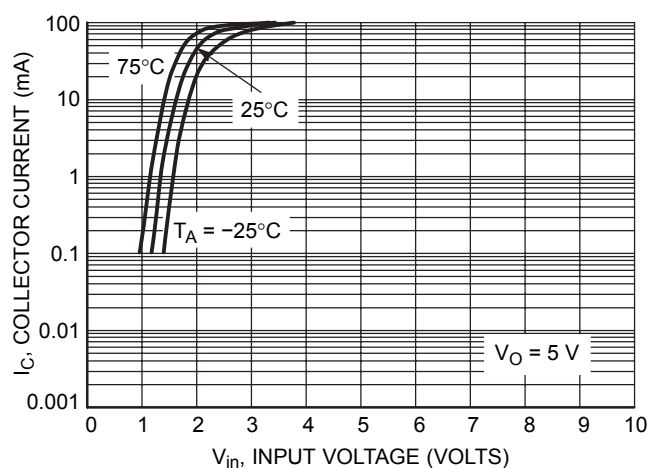


Figure 11. Output Current versus Input Voltage

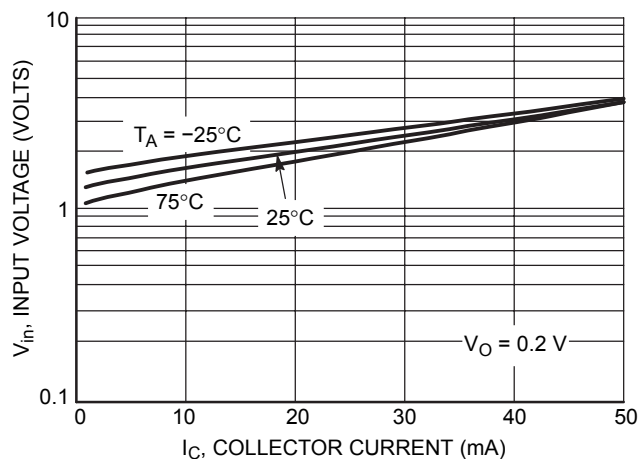


Figure 12. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS – DTC124EE

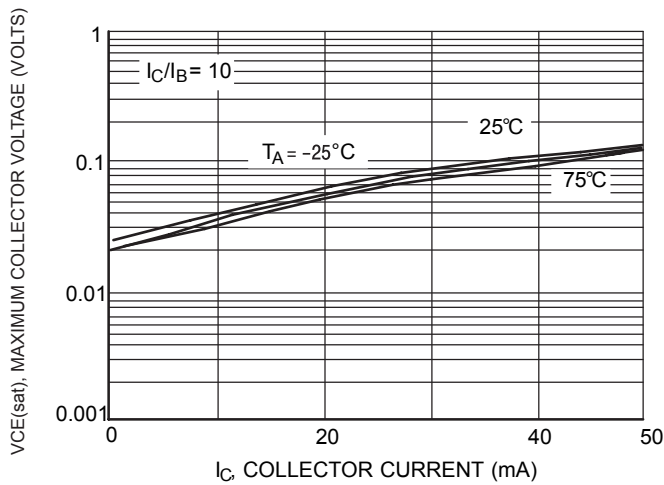


Figure 13. $V_{CE(sat)}$ versus I_C

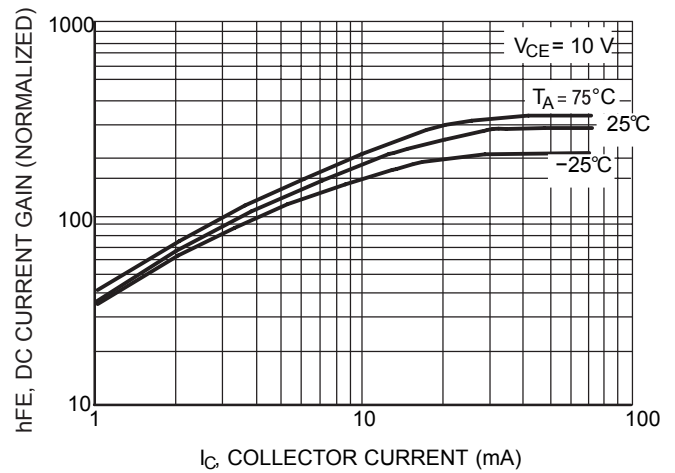


Figure 14. DC Current Gain

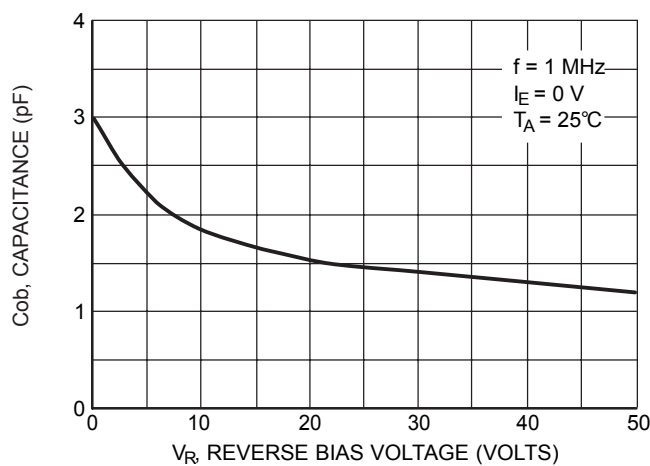


Figure 15. Output Capacitance

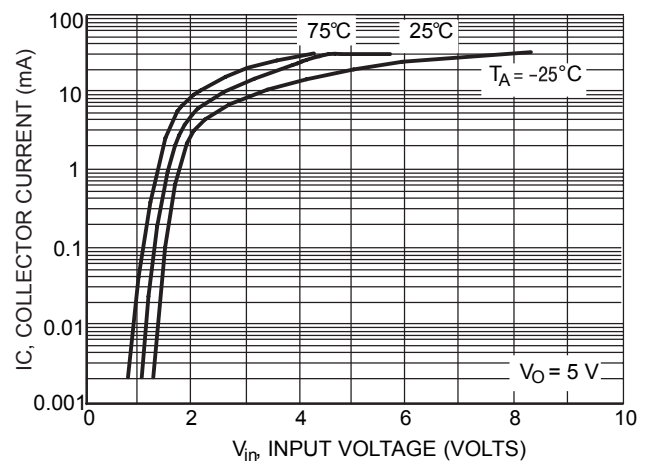


Figure 16. Output Current versus Input Voltage

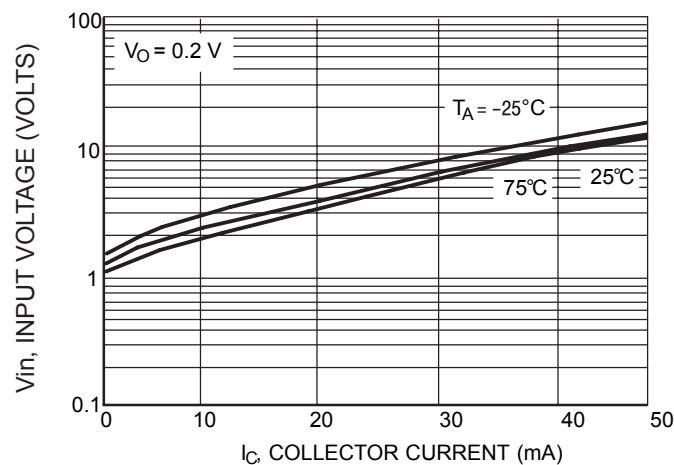


Figure 17. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS – DTC114EE

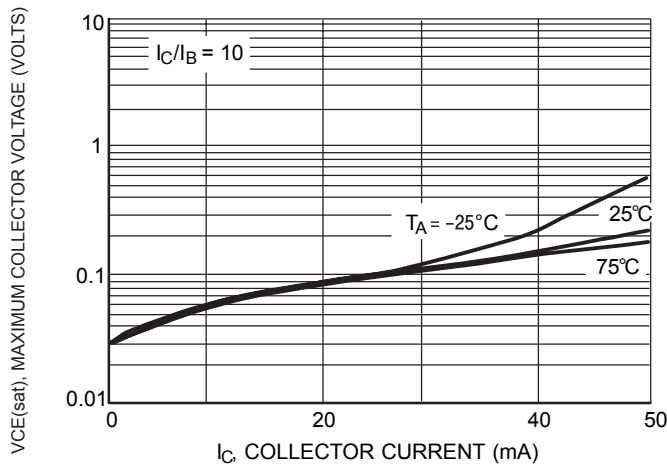


Figure 18. $V_{CE(sat)}$ versus I_C

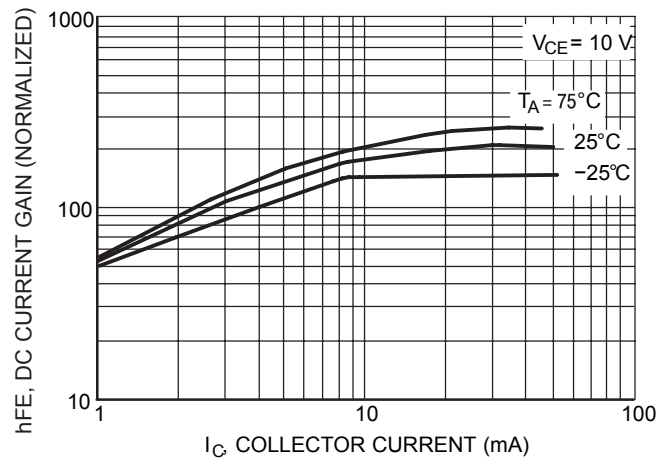


Figure 19. DC Current Gain

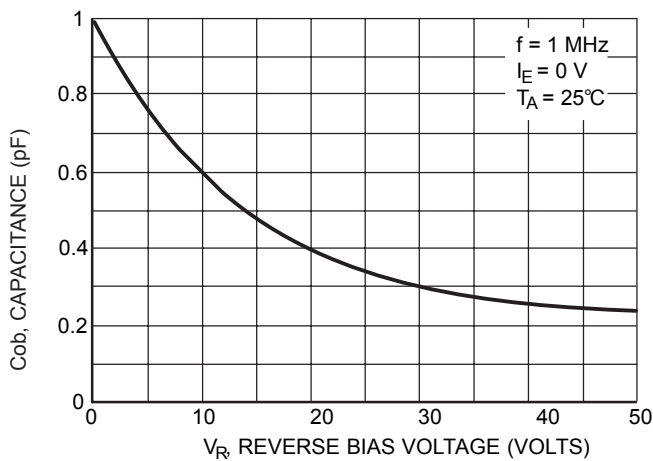


Figure 20. Output Capacitance

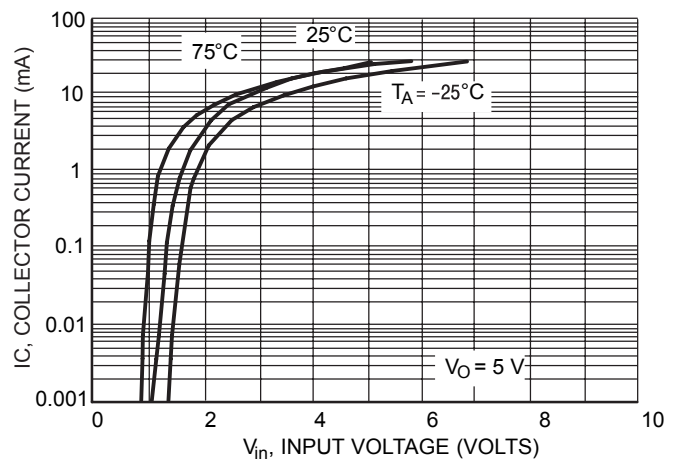


Figure 21. Output Current versus Input Voltage

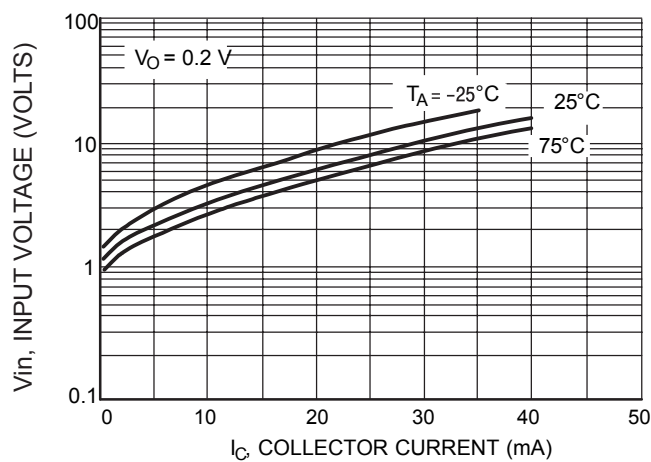


Figure 22. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS – DTC114YE

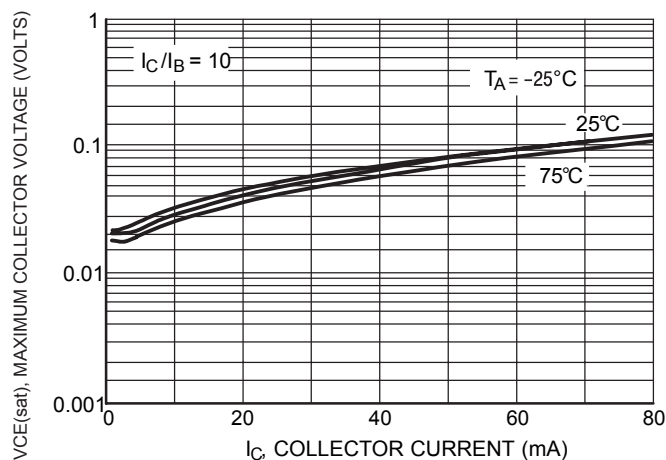


Figure 23. $V_{CE(sat)}$ versus I_C

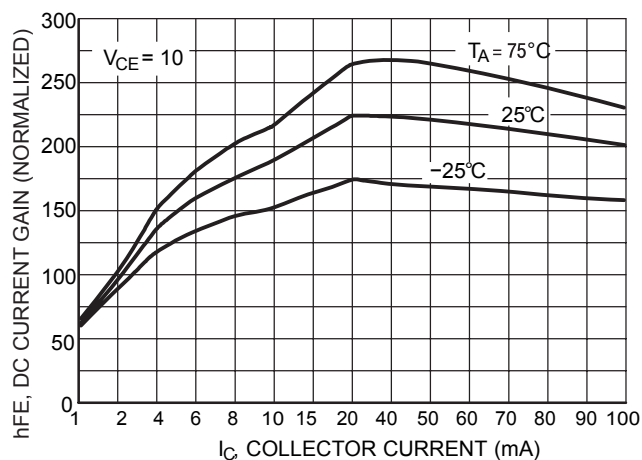


Figure 24. DC Current Gain

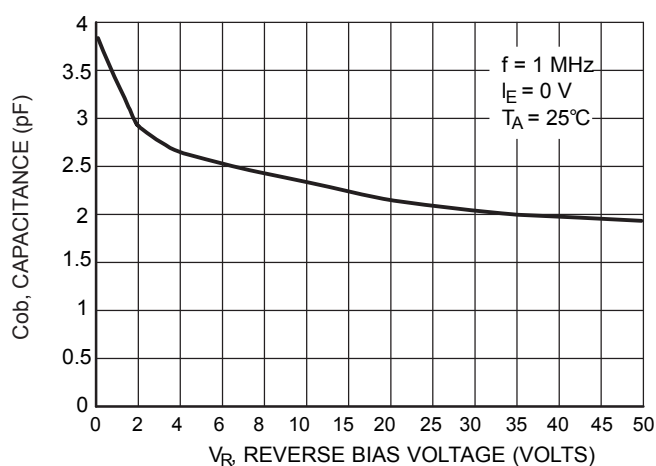


Figure 25. Output Capacitance

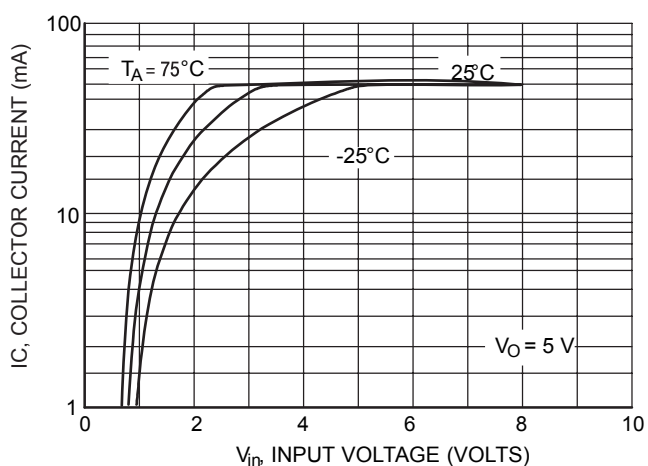


Figure 26. Output Current versus Input Voltage

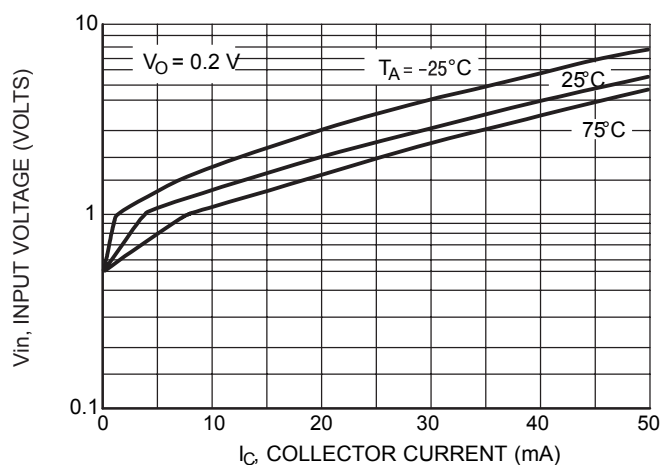


Figure 27. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS — DTA115EE1

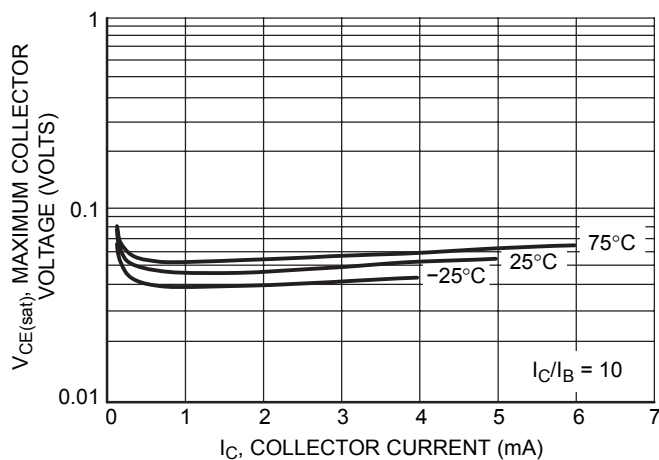


Figure 29. Maximum Collector Voltage versus Collector Current

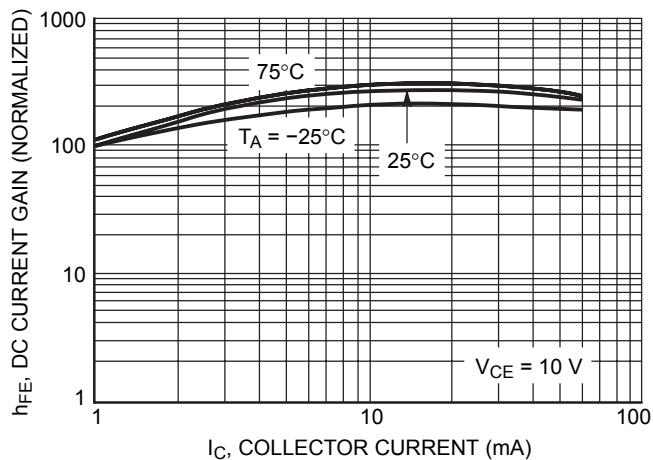


Figure 30. DC Current Gain

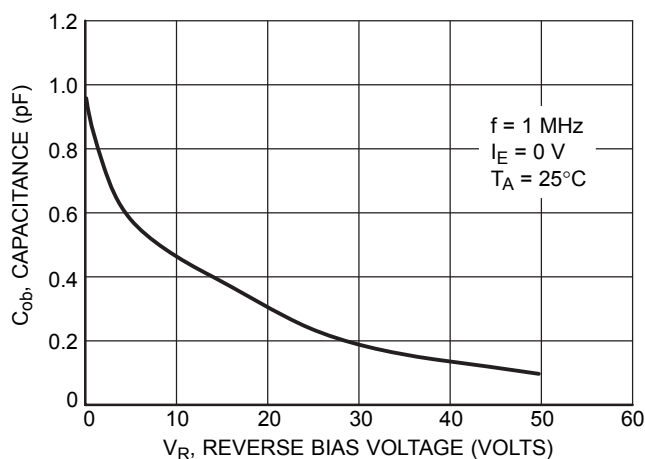


Figure 31. Output Capacitance

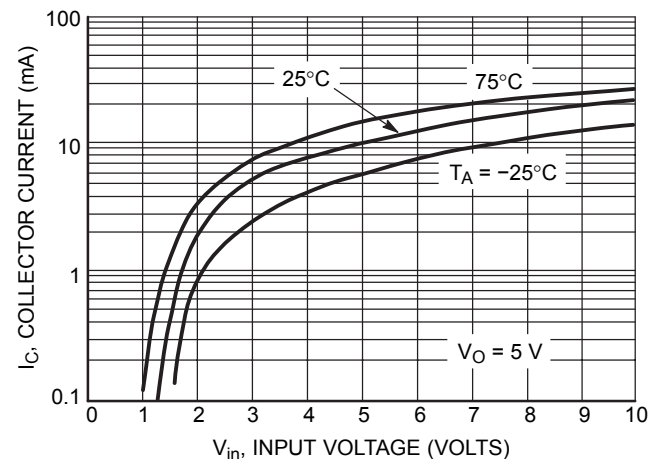


Figure 32. Output Current versus Input Voltage

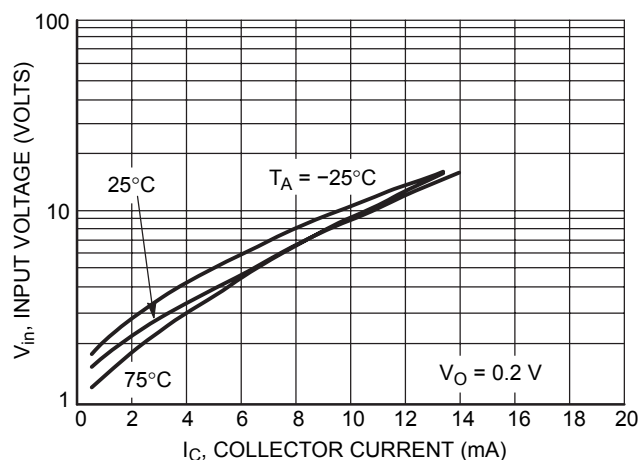


Figure 33. Input Voltage versus Output Current

TYPICAL APPLICATIONS FOR NPN BRTs

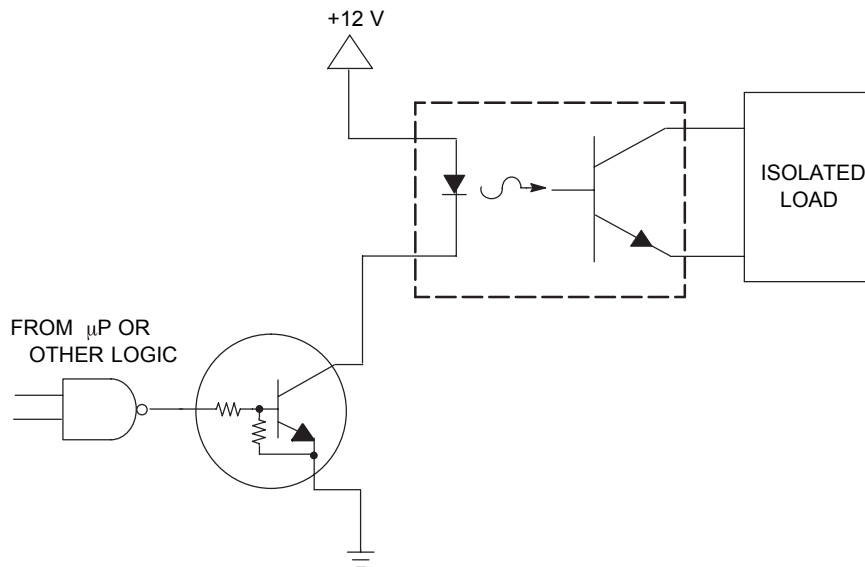


Figure 28. Level Shifter: Connects 12 or 24 Volt Circuits to Logic

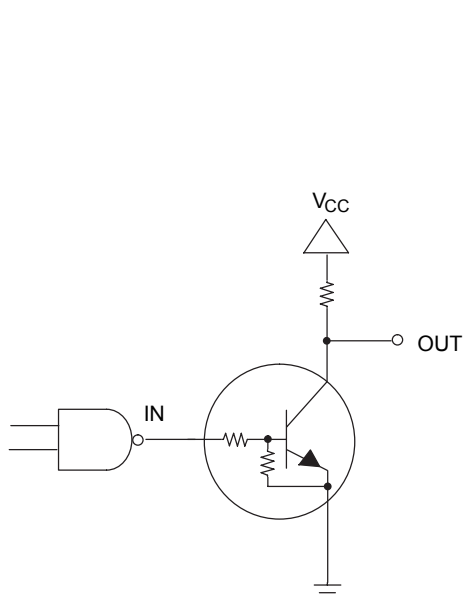


Figure 29. Open Collector Inverter:
Inverts the Input Signal

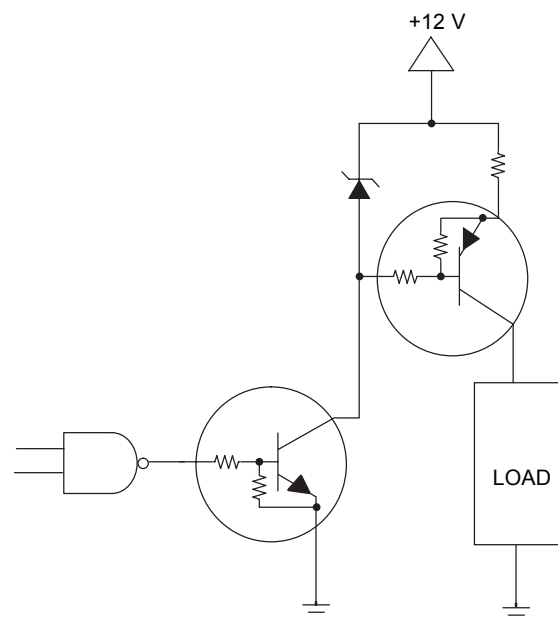
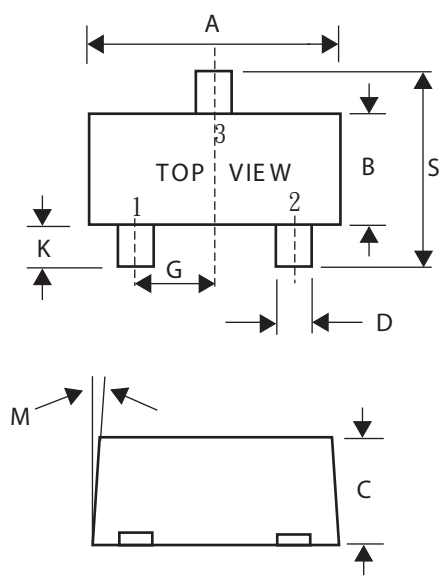


Figure 30. Inexpensive, Unregulated Current Source

SC-89 Outline Demensions

Unit:mm



SC-89			
Dim	Min	Nom	Max
A	1.50	1.60	1.70
B	0.75	0.85	0.95
C	0.60	0.70	0.80
D	0.23	0.28	0.33
G	0.50BSC		
J	0.10	0.15	0.20
K	0.30	0.40	0.50
M	---	---	10°
N	---	---	10°
S	1.50	1.60	1.70